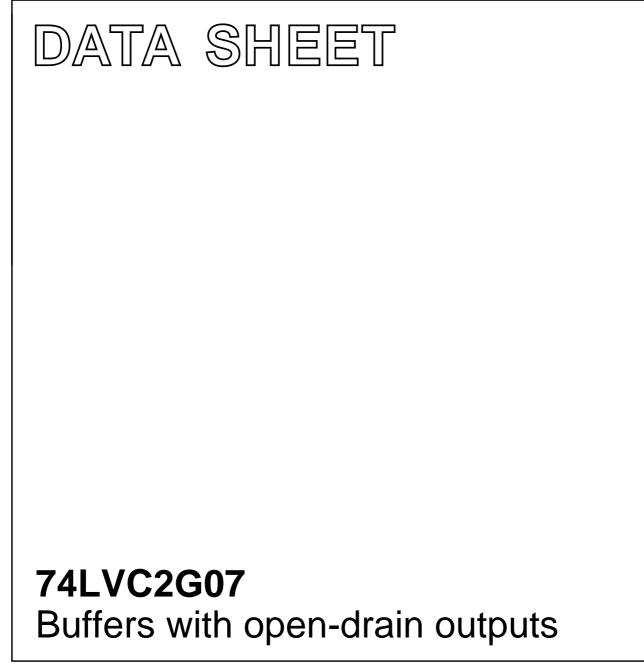
INTEGRATED CIRCUITS



Product specification Supersedes data of 2004 Mar 19 2004 Sep 08



HILIP

74LVC2G07

FEATURES

- Wide supply voltage range from 1.65 V to 5.5 V
- 5 V tolerant input/output for interfacing with 5 V logic
- High noise immunity
- Complies with JEDEC standard:
 - JESD8-7 (1.65 V to 1.95 V)
 - JESD8-5 (2.3 V to 2.7 V)
 - JESD8B/JESD36 (2.7 V to 3.6 V).
- –24 mA output drive (V_{CC} = 3.0 V)
- CMOS low power consumption
- Latch-up performance exceeds 250 mA
- Direct interface with TTL levels
- Inputs accept voltages up to 5 V
- Multiple package options
- ESD protection:
 - HBM EIA/JESD22-A114-B exceeds 2000 V
 - MM EIA/JESD22-A115-A exceeds 200 V.
- Specified from -40 °C to +85 °C and -40 °C to +125 °C.

QUICK REFERENCE DATA

GND = 0 V; T_{amb} = 25 °C.

DESCRIPTION

The 74LVC2G07 is a high-performance, low-power, low-voltage, Si-gate CMOS device superior to most advanced CMOS compatible TTL families.

Input can be driven from either 3.3 V or 5 V devices. This feature allows the use of this device in a mixed 3.3 V and 5 V environment.

Schmitt trigger action at all inputs makes the circuit tolerant for slower input rise and fall time.

This device is fully specified for partial power-down applications using I_{off} . The I_{off} circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

The 74LVC2G07 provides two non-inverting buffers.

The output of the device is an open drain and can be connected to other open-drain outputs to implement active-LOW wired-OR or active-HIGH wired-AND functions.

SYMBOL	PARAMETER	CONDITIONS	TYPICAL	UNIT
t _{PLZ} /t _{PZL}	propagation delay input nA to output nY	V_{CC} = 1.8 V; C_L = 30 pF; R_L = 1 k Ω	3.5	ns
		$V_{CC} = 2.5 \text{ V}; \text{ C}_{L} = 30 \text{ pF}; \text{ R}_{L} = 500 \Omega$	2.4	ns
		$V_{CC} = 2.7 \text{ V}; \text{ C}_{L} = 50 \text{ pF}; \text{ R}_{L} = 500 \Omega$	2.3	ns
		$V_{CC} = 3.3 \text{ V}; \text{ C}_{L} = 50 \text{ pF}; \text{ R}_{L} = 500 \Omega$	2.6	ns
		$V_{CC} = 5.0 \text{ V}; \text{ C}_{L} = 50 \text{ pF}; \text{ R}_{L} = 500 \Omega$	1.5	ns
Cl	input capacitance		2.5	pF
C _{PD}	power dissipation capacitance per gate	V_{CC} = 3.3 V; notes 1 and 2	6.5	pF

Notes

1. C_{PD} is used to determine the dynamic power dissipation (P_D in μ W).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum (C_L \times V_{CC}^2 \times f_o)$ where:

 f_i = input frequency in MHz;

f_o = output frequency in MHz;

 C_L = output load capacitance in pF;

 V_{CC} = supply voltage in Volts;

N = total load switching outputs;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of outputs.

2. The condition is $V_I = GND$ to V_{CC} .

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FUNCTION TABLE

See note 1.

INPUT	OUTPUT
nA	nY
L	L
Н	Z

Note

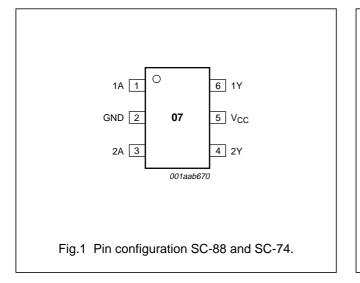
- 1. H = HIGH voltage level;
 - L = LOW voltage level;
 - Z = high-impedance OFF-state.

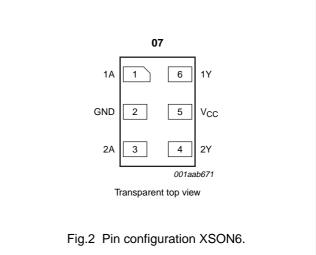
ORDERING INFORMATION

TYPE NUMBER	PACKAGE							
	TEMPERATURE RANGE	PINS	PACKAGE	MATERIAL	CODE	MARKING		
74LVC2G07GW	–40 °C to +125 °C	6	SC-88	plastic	SOT363	V7		
74LVC2G07GV	–40 °C to +125 °C	6	SC-74	plastic	SOT457	V07		
74LVC2G07GM	–40 °C to +125 °C	6	XSON6	plastic	SOT886	V7		

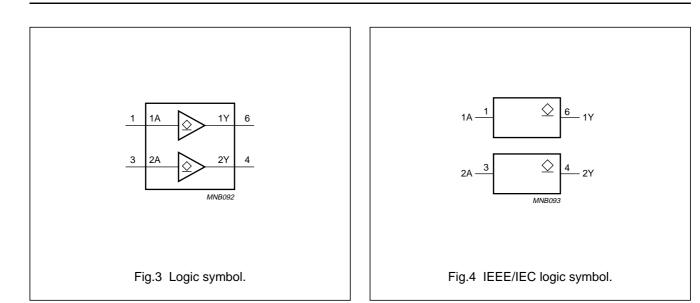
PINNING

PIN	SYMBOL	DESCRIPTION
1	1A	data input
2	GND	ground (0 V)
3	2A	data input
4	2Y	data output
5	V _{CC}	supply voltage
6	1Y	data output





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RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CC}	supply voltage		1.65	5.5	V
VI	input voltage		0	5.5	V
Vo	output voltage	active mode	0	V _{CC}	V
		V _{CC} = 0 V; Power-down mode	0	5.5	V
T _{amb}	operating ambient temperature		-40	+125	°C
t _r , t _f	input rise and fall times	$V_{CC} = 1.65 \text{ V to } 2.7 \text{ V}$	0	20	ns/V
		$V_{CC} = 2.7 \text{ V to } 5.5 \text{ V}$	0	10	ns/V

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134); voltages are referenced to GND (ground = 0 V).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CC}	supply voltage		-0.5	+6.5	V
I _{IK}	input diode current	V ₁ < 0 V	_	-50	mA
VI	input voltage	note 1	-0.5	+6.5	V
I _{OK}	output diode current	V _O < 0 V	-	-50	mA
Vo	output voltage	active mode; notes 1 and 2	-0.5	+6.5	V
		Power-down mode; notes 1 and 2	-0.5	+6.5	V
lo	output source or sink current	$V_0 = 0 V \text{ to } 6.5 V$	-	50	mA
I _{CC} , I _{GND}	V _{CC} or GND current		-	±100	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	power dissipation	$T_{amb} = -40 \text{ °C to } +125 \text{ °C}$	_	300	mW

Notes

1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

2. When V_{CC} = 0 V (Power-down mode), the output voltage can be 5.5 V in normal operation.

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DC CHARACTERISTICS

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

evmp.el	PARAMETER	TEST COND	ITIONS	– MIN.	TVD		
SYMBOL		OTHER	V _{CC} (V)		TYP.	MAX.	
T _{amb} = -40) °C to +85 ° C ; note 1						
V _{IH}	HIGH-level input voltage		1.65 to 1.95	$0.65 \times V_{CC}$	_	-	V
			2.3 to 2.7	1.7	-	-	V
			2.7 to 3.6	2.0	-	-	V
			4.5 to 5.5	$0.7 \times V_{CC}$	-	-	V
V _{IL}	LOW-level input voltage		1.65 to 1.95	_	-	$0.35 \times V_{CC}$	V
			2.3 to 2.7	_	-	0.7	V
			2.7 to 3.6	_	-	0.8	V
			4.5 to 5.5	_	-	$0.3 \times V_{CC}$	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$					
		I _O = 100 μA	1.65 to 5.5	-	-	0.1	V
		I _O = 4 mA	1.65	-	-	0.45	V
		I _O = 8 mA	2.3	-	-	0.3	V
		I _O = 12 mA	2.7	-	-	0.4	V
		I _O = 24 mA	3.0	-	-	0.55	V
		I _O = 32 mA	4.5	-	-	0.55	V
ILI	input leakage current	$V_{I} = 5.5 V \text{ or GND}$	1.65 to 5.5	-	±0.1	±5	μA
I _{OZ}	output OFF-state current	$V_{I} = V_{IH} \text{ or } V_{IL};$ $V_{O} = V_{CC} \text{ or } GND$	5.5	-	±0.1	±10	μA
l _{off}	power OFF leakage current	$V_1 \text{ or } V_0 = 5.5 \text{ V}$	0	-	±0.1	±10	μA
I _{CC}	quiescent supply current	$V_{I} = V_{CC}$ or GND; $I_{O} = 0 \text{ A}$	5.5	-	0.1	10	μA
ΔI_{CC}	additional quiescent supply current per pin	$V_{I} = V_{CC} - 0.6 \text{ V};$ $I_{O} = 0 \text{ A}$	2.3 to 5.5	-	5	500	μA

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		TEST COND	ITIONS					
SYMBOL	PARAMETER	OTHER	V _{CC} (V)	MIN.	TYP.	MAX.	UNIT	
T _{amb} = -40	0 °C to +125 °C				•			
VIH	HIGH-level input voltage		1.65 to 1.95	$0.65 \times V_{CC}$	_	-	V	
			2.3 to 2.7	1.7	_	-	V	
			2.7 to 3.6	2.0	-	-	V	
			4.5 to 5.5	$0.7 \times V_{CC}$	-	-	V	
V _{IL}	LOW-level input voltage		1.65 to 1.95	_	-	$0.35 imes V_{CC}$	V	
			2.3 to 2.7	-	-	0.7	V	
			2.7 to 3.6	_	-	0.8	V	
			4.5 to 5.5	_	-	$0.3 \times V_{CC}$	V	
V _{OL}	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$						
		I _O = 100 μA	1.65 to 5.5	_	-	0.1	V	
		I _O = 4 mA	1.65	_	-	0.70	V	
		I _O = 8 mA	2.3	_	-	0.45	V	
		l _O = 12 mA	2.7	_	-	0.60	V	
		I _O = 24 mA	3.0	_	-	0.80	V	
		I _O = 32 mA	4.5	-	-	0.80	V	
ILI	input leakage current	$V_{I} = 5.5 \text{ V or GND}$	1.65 to 5.5	_	-	±20	μA	
I _{OZ}	output OFF-state current	$V_{I} = V_{IH} \text{ or } V_{IL};$ $V_{O} = V_{CC} \text{ or } GND$	5.5	-	-	±10	μA	
l _{off}	power OFF leakage current	$V_{\rm I}$ or $V_{\rm O}$ = 5.5 V	0	-	-	±20	μA	
I _{CC}	quiescent supply current	$V_{I} = V_{CC}$ or GND; $I_{O} = 0 \text{ A}$	5.5	-	-	40	μA	
ΔI_{CC}	additional quiescent supply current per pin	$V_{I} = V_{CC} - 0.6 \text{ V};$ $I_{O} = 0 \text{ A}$	2.3 to 5.5	-	-	5000	μA	

Note

1. All typical values are measured at V_{CC} = 3.3 V and T_{amb} = 25 °C.

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AC CHARACTERISTICS

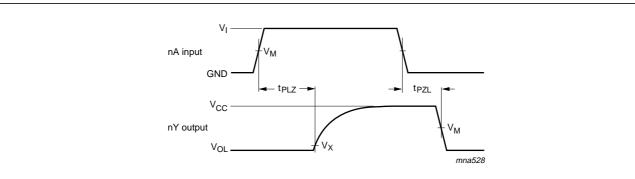
GND = 0 V.

		TEST CON	DITIONS	RAINI	TVD	MAX.			
SYMBOL	PARAMETER	WAVEFORMS	V _{CC} (V)	MIN.	TYP.		UNIT		
T _{amb} = -40	T _{amb} = -40 °C to +85 °C; note 1								
t _{PLZ} /t _{PZL}	t _{PLZ} /t _{PZL} propagation delay input nA to output nY	see Figs 5 and 6	1.65 to 1.95	1.0	3.5	6.7	ns		
			2.3 to 2.7	0.5	2.4	4.3	ns		
			2.7	1.0	2.3	4.2	ns		
			3.0 to 3.6	0.5	2.6	3.7	ns		
			4.5 to 5.5	0.5	1.5	2.9	ns		
T _{amb} = -40) °C to +125 °C								
t _{PLZ} /t _{PZL}	propagation delay input nA to	see Figs 5 and 6	1.65 to 1.95	1.0	3.5	8.4	ns		
	output nY		2.3 to 2.7	0.5	2.4	5.5	ns		
			2.7	1.0	2.3	5.3	ns		
			3.0 to 3.6	0.5	2.6	4.7	ns		
			4.5 to 5.5	0.5	1.5	3.7	ns		

Note

1. All typical values are measured at T_{amb} = 25 °C and at V_{CC} = 1.8 V, 2.5 V, 2.7 V, 3.3 V and 5.0 V respectively.

AC WAVEFORMS

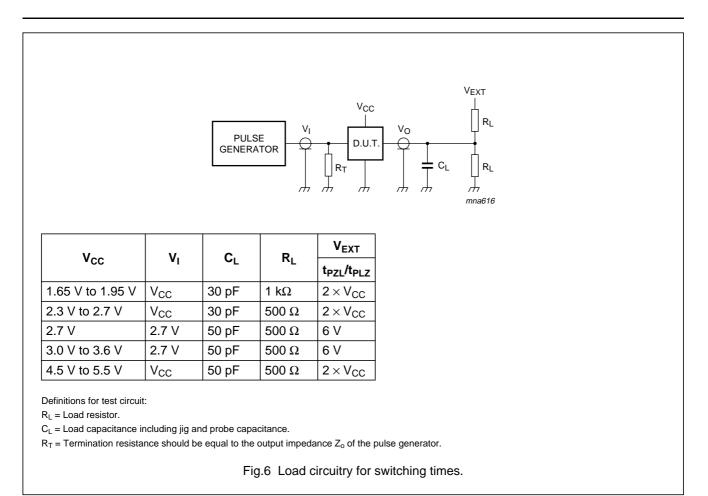


Vee	Mara Mara Mar		INPUT		
V _{CC}	V _M	Vx	VI	t _r = t _f	
1.65 V to 1.95 V	$0.5 \times V_{CC}$	V _{OL} + 0.15 V	V _{CC}	≤ 2.0 ns	
2.3 V to 2.7 V	$0.5 imes V_{CC}$	V _{OL} + 0.15 V	V _{CC}	≤ 2.0 ns	
2.7 V	1.5 V	V _{OL} + 0.3 V	2.7 V	≤ 2.5 ns	
3.0 V to 3.6 V	1.5 V	V _{OL} + 0.3 V	2.7 V	≤ 2.5 ns	
4.5 V to 5.5 V	$0.5 imes V_{CC}$	V _{OL} + 0.3 V	V _{CC}	≤ 2.5 ns	

 V_{OL} and V_{OH} are typical output voltage drop that occur with the output load.

Fig.5 Input nA to output nY propagation delays.

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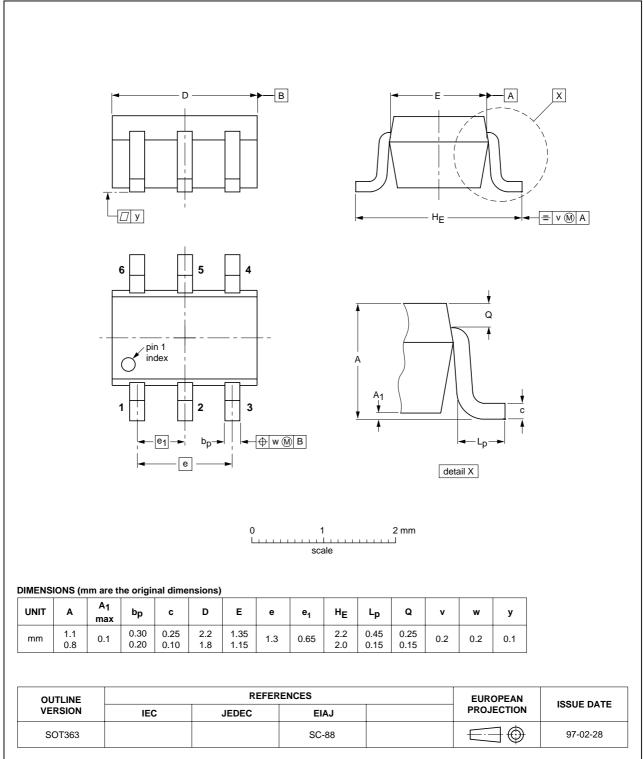


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Buffers with open-drain outputs

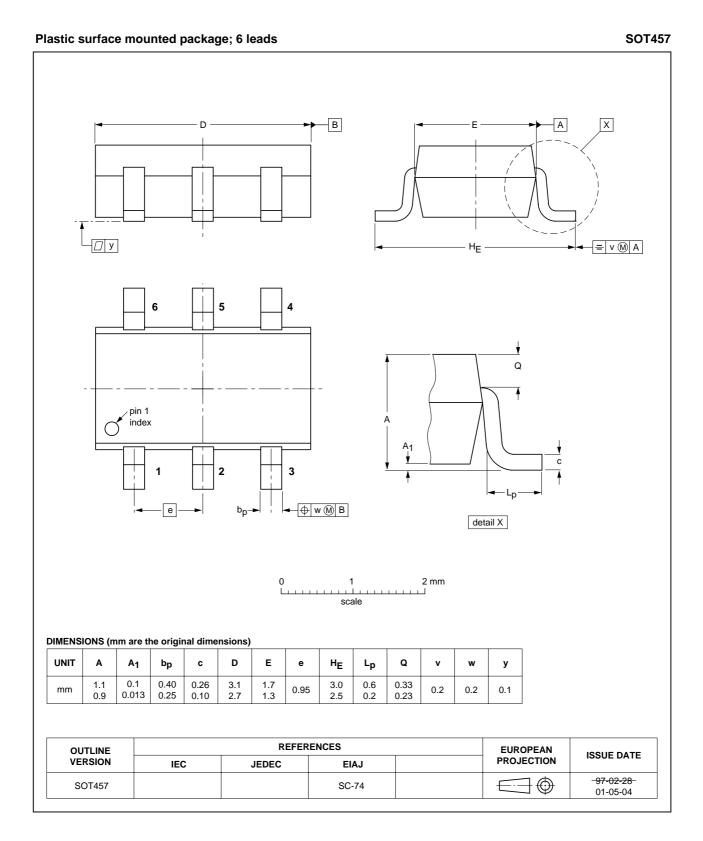
PACKAGE OUTLINES



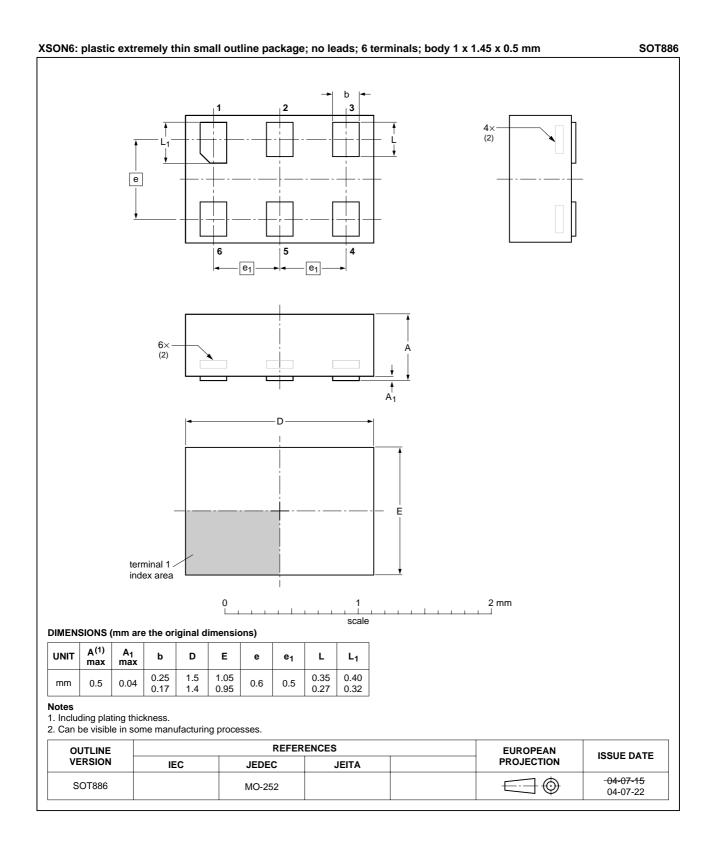


SOT363

74LVC2G07



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LEVEL	DATA SHEET STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾⁽³⁾	DEFINITION
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